

Features:

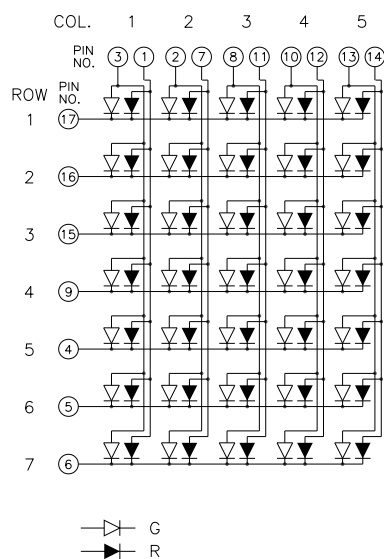
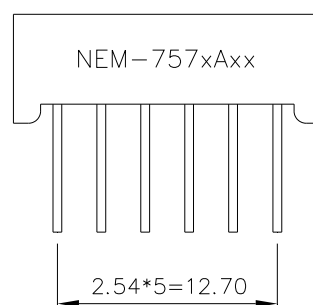
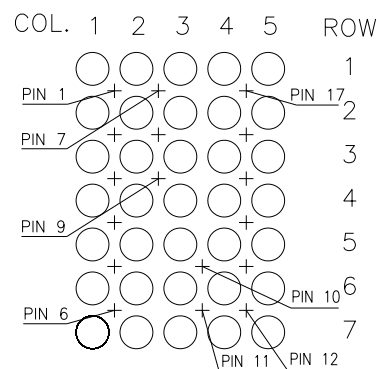
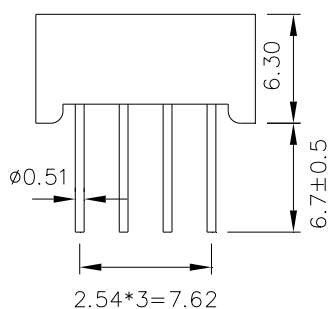
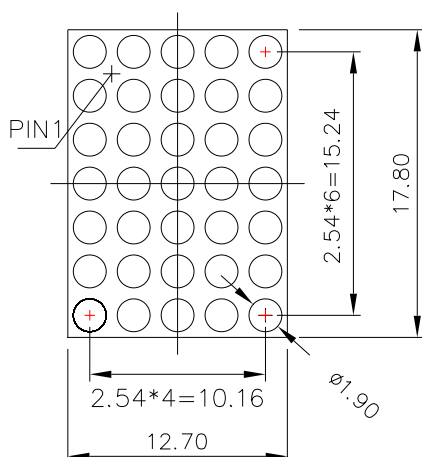
- Large emitting dot 1.9mm diameter.
- Low current operation.
- Easy mounting on P.C. boards or sockets.
- Wide viewing angle.
- Solid state reliability.
- Mechanically rugged.
- Pb free.
- RoHS compliant.

Descriptions:

- The NEM-757xAxx series is a large emitting area (1.9mm diameter) LED sources configured in a 35 dot 5*7 matrix array.
- These devices are made with black surface and white segments.
- The Super Bright Red source color devices are made with AlGaInP Red Light Emitting Diode
The Green source color devices are made with Gallium Phosphide Green Light Emitting Diode

Part No.: NEM-7571ASG-11

Package Dimensions & Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters(inches),Tolerance is ± 0.25 (0.01”) unless otherwise noted.
2. Specifications are subject to change without notice.

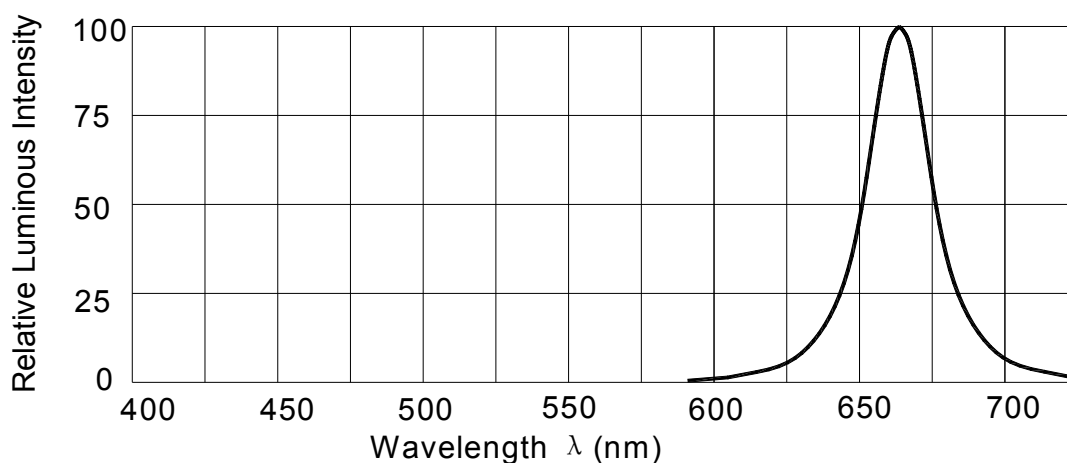
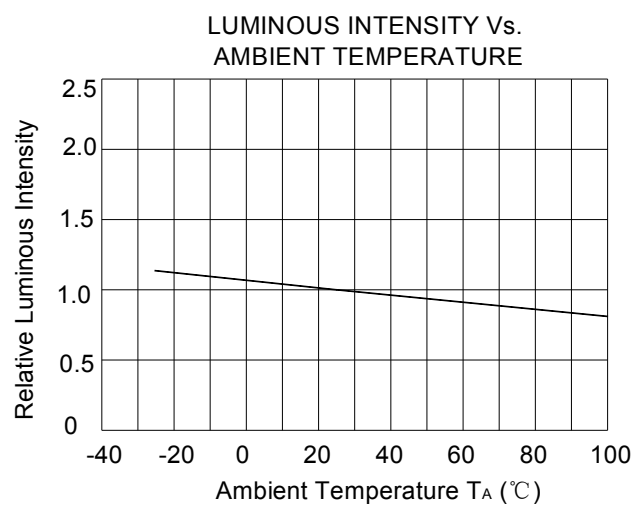
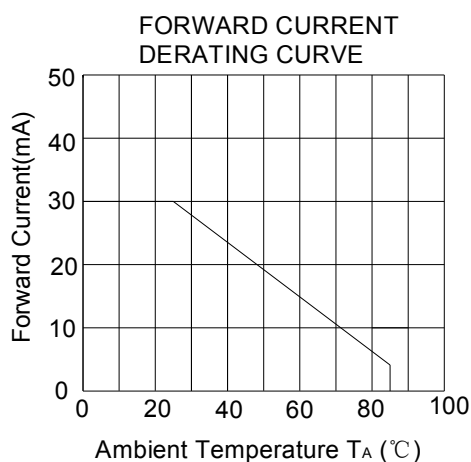
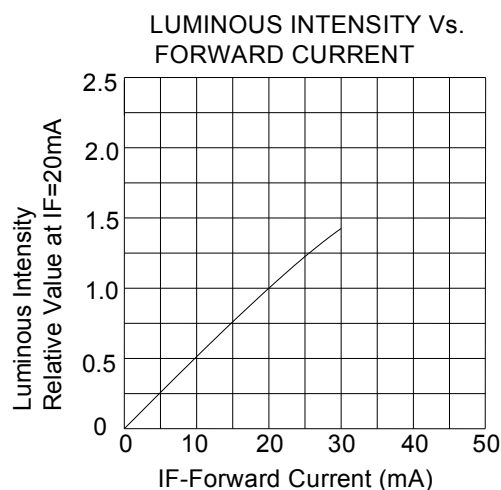
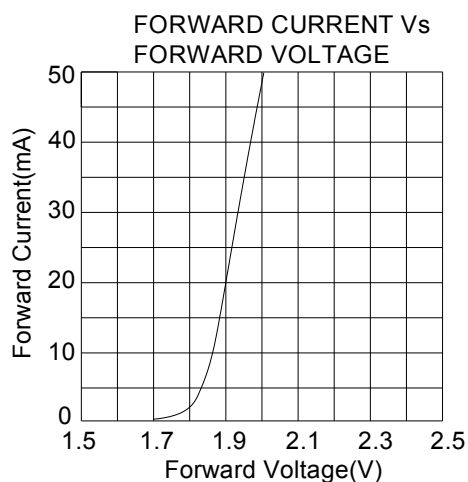
Absolute maximum ratings (Ta = 25℃)

Parameter	Symbol		Value		Unit
			Min.	Max.	
Reverse Voltage	VR	----	----	5	V
Forward Current	IF	----	----	25	mA
Power Dissipation	Pd	----	----	60	mW
Pulse Current	Ipeak	Duty=0.1mS, 1kHz	----	80	mA
Operating Temperature	Topr	----	-25	+85	℃
Storage Temperature	Tstr	----	-30	+85	℃
Solder Temperature	Tsol	1/16inch below Seating plane	260/3		℃/s

Electrical and optical characteristics (Ta = 25℃)

Parameter	Symbol	Color	Test Condition	Values			Unit
				Min.	Typ.	Max.	
Forward Voltage	VF	S	IF=20mA	----	2.0	2.4	V
		G		----	2.3	2.6	
Reverse Current	IR		VR=5V	----	----	30	μ A
Dominate Wavelength	λ d	S	IF=20mA	----	640	----	nm
		G		----	570	----	
Peak Wavelength	λ p	S	IF=20mA	----	660	----	nm
		G		----	568	----	
Spectral Line half-width	Δ λ	S	IF=20mA	----	20	----	nm
		G		----	30	----	
Luminous Intensity	Iv	S	IF=10mA	----	3500	----	ucd
		G		----	2500	----	

Typical electrical/optical characteristic curves:



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